

BCR4CM-16LH

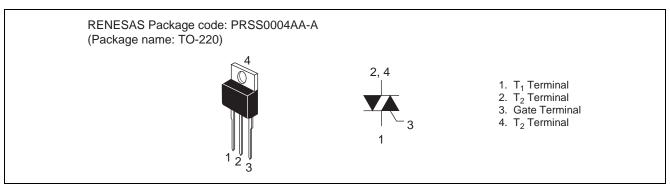
Triac Medium Power Use R07DS0255EJ0100 Rev.1.00 Feb 28, 2011

Features

- I_{T (RMS)}: 4 A
 V_{DRM}: 800 V
- $\bullet \quad I_{FGTI},\,I_{RGT\,III}\colon 35\,\,\text{mA or}\,\,10\text{mA}(I_{GT}\,item:1)$
- High Commutation

- The Product guaranteed maximum junction temperature 150°C
- Planar Type

Outline



Applications

Switching mode power supply, small motor control, heater control, and other general purpose AC power control applications

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
Farameter	Syllibol	16	Offic
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	800	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	960	V

Notes: 1. Gate open.

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	4	А	Commercial frequency, sine full wave 360°conduction, Tc = 132°C Note3
Surge on-state current	I _{TSM}	30	Α	60 Hz sinewave 1 full cycle, peak value, non-repetitive
I ² t for fusion	l ² t	3.7	A ² s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	P_{GM}	3	W	
Average gate power dissipation	P _{G (AV)}	0.3	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I _{GM}	2	Α	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	
Mass	_	2.0	g	Typical value

Notes: 1. Gate open.

Electrical Characteristics

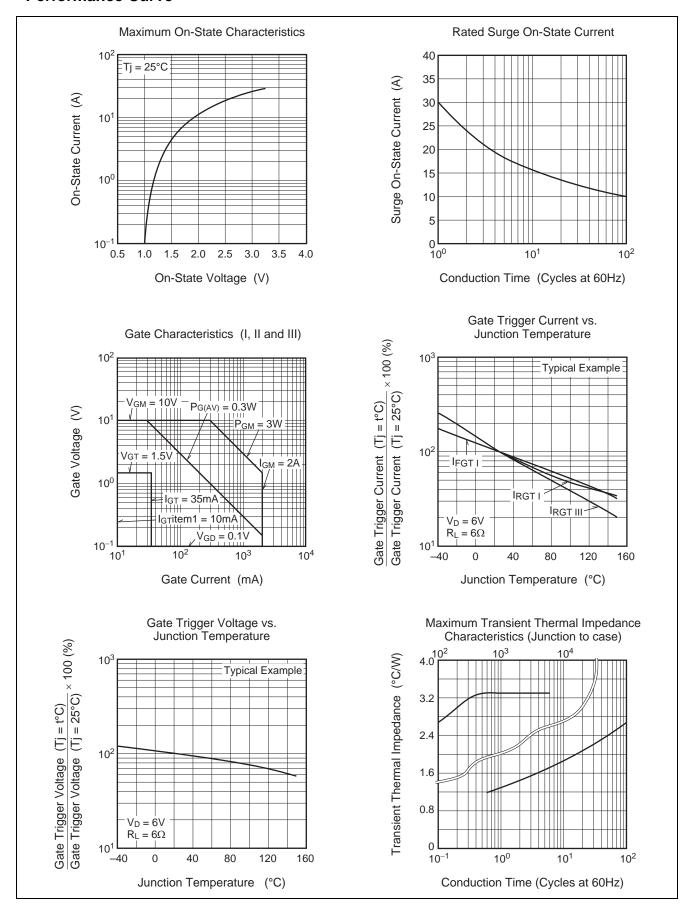
Parameter		Symbol	BCR4CM-16LH-1 (I _{GT} item: 1)		BCR4CM-16LH			Unit	Test conditions	
			Min.	Тур.	Max.	Min.	Тур.	Max.		
Repetitive peak off-state co	urrent	I _{DRM}		ı	2.0	ı	_	2.0	mA	Tj = 150°C V _{DRM} applied
On-state voltage		V _{TM}			1.6		_	1.6	>	Tc = 25°C, I _{TM} = 6 A instantaneous measurement
Gate trigger voltage ^{Note2}	I	V_{FGTI}	_		1.5			1.5	V	$Tj = 25^{\circ}C, V_D = 6 V$
	II	V_{RGTI}	_		1.5			1.5	V	$R_L = 6 \Omega$, $R_G = 330 \Omega$
	III	V_{RGTIII}			1.5	_		1.5	٧	
Gate trigger curent ^{Note2}	I	I_{FGTI}	_	_	10	_	_	35	mA	$Tj = 25^{\circ}C, V_D = 6 V$
	II	I_{RGTI}	_		10			35	mA	$R_L = 6 \Omega$, $R_G = 330 \Omega$
	III	I _{RGTIII}		_	10	_	_	35	mA	
Gate non-trigger voltage		V_{GD}	0.2			0.2	_	_	٧	$Tj = 125^{\circ}C$ $V_D = 1/2 V_{DRM}$
			0.1			0.1	_	_	٧	$Tj = 150^{\circ}C$ $V_D = 1/2 V_{DRM}$
Thermal resistance		R _{th (j-c)}	_	_	3.3	_	_	3.3	°C/W	Junction to case ^{Note3,4}
		(di/dt)c	2.5	_	_	_		_	A/ms	Tj = 125°C (dv/dt)c < 10 V/μs
					1	3.0		_	A/ms	Tj = 125°C (dv/dt)c < 100 V/μs

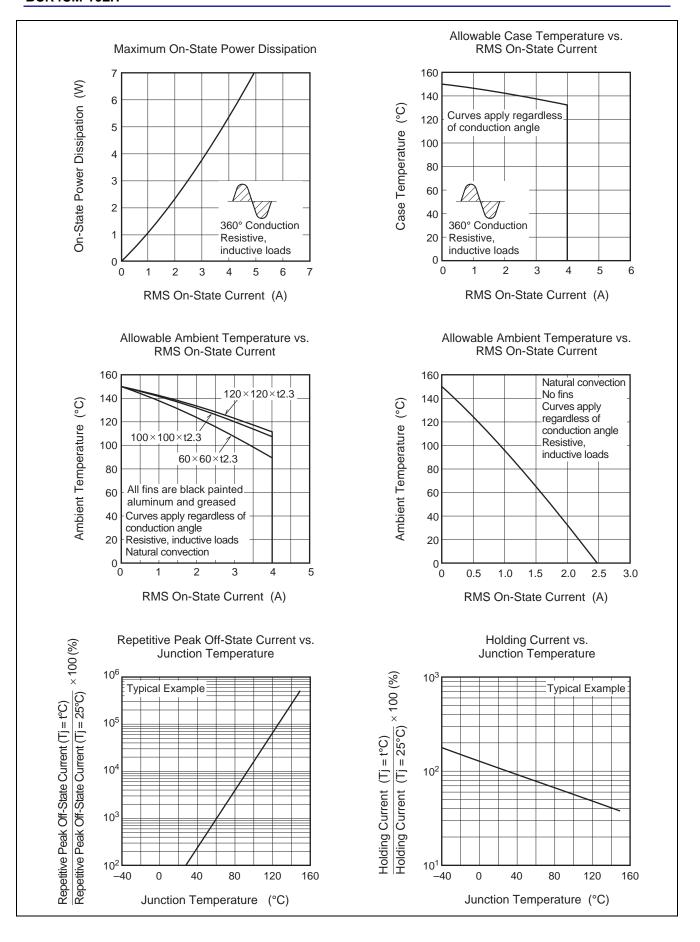
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

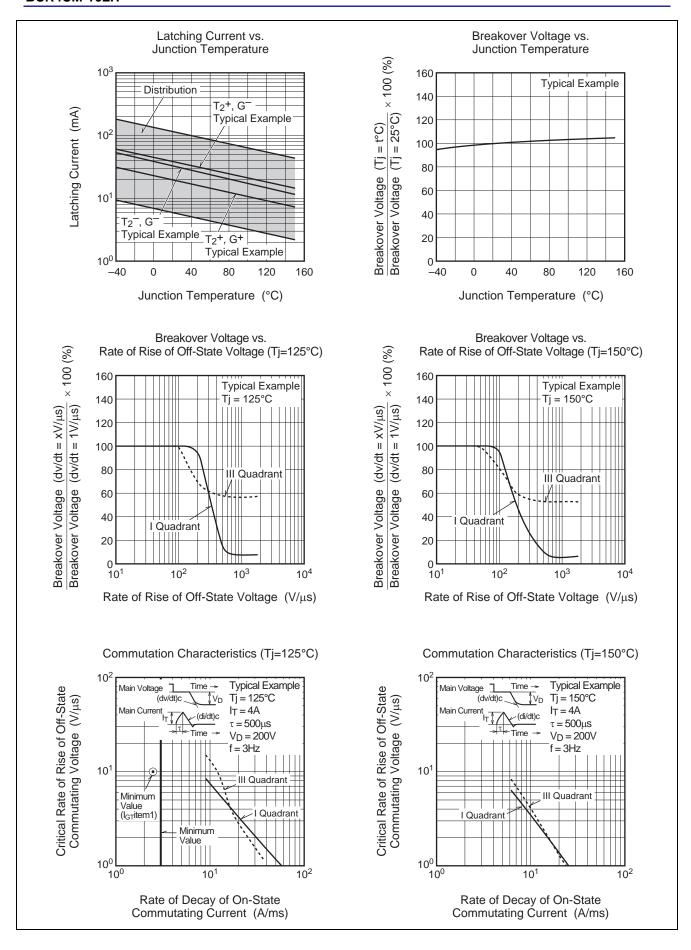
- 3. Case temperature is measured at the T_2 tab 1.5 mm apart from the molded case.
- 4. The contact thermal resistance $R_{\text{th (c-f)}}$ in case of greasing is 1.0°C/W.
- 5. Test conditions of the critical-rate of decay of on-state commutation current are shown in the table below.

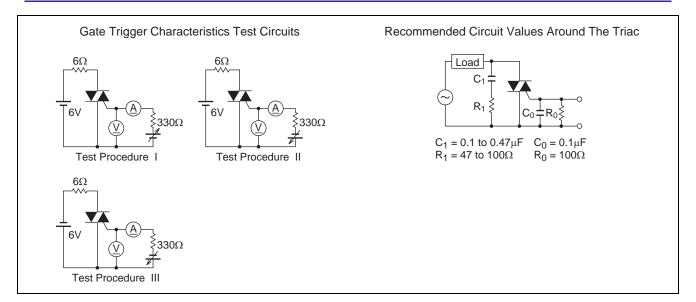
Test conditions	Commutating voltage and current waveforms (inductive load)
 Junction temperature Tj = 125°C Peak off-state voltage V_D = 400 V Rate of rise of off-state commutating voltage (dv/dt)c < 10 V/μs (I_{GT} item : 1) (dv/dt)c < 100 V/μs 	Supply Voltage Main Current Main Voltage (dv/dt)c Time VD

Performance Curve

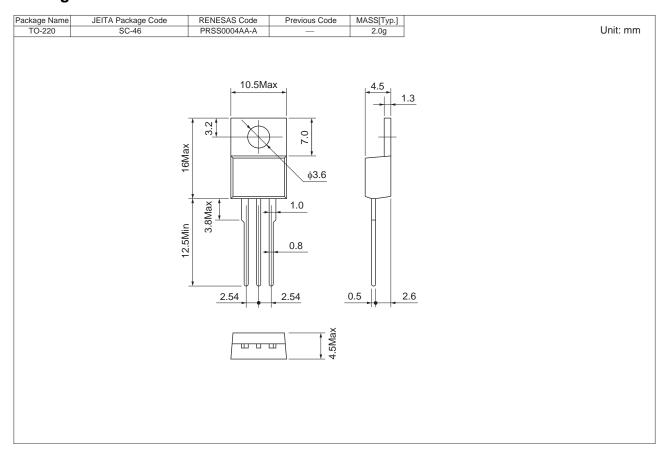








Package Dimensions



Ordering Information

Orderable Part Number	Packing	Quantity	Remark	
BCR4CM-16LH#B00	Bag	100 pcs.	Straight type	
BCE4CM-16LH-1#B00	Bag	100 pcs.	Straight type, IGT item1	

Note: Please confirm the specification about the shipping in detail.

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